## NSN 5961-01-017-8763

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-017-8763 **Inclosure Material:** Metal **Overall Length:** 0.410 inches **Overall Diameter:** 1.540 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Gold plated leads and hermetically sealed case **Semiconductor Material:** Silicon **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Precious Material And Location:** Terminals gold **Test Data Document:** 82577-928791 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Yes - demil/mli

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